NSN 5961-01-253-6720

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Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-253-6720

view Online at https://aerobasegroup.com/nsn/5961-01-255-6720
Inclosure Material:
Ceramic or glass or metal
Overall Length:
Between 0.335 inches and 0.370 inches
Terminal Length:
Between 1.500 inches and 1.750 inches
Overall Height:
Between 0.240 inches and 0.260 inches
Overall Diameter:
Between 0.305 inches and 0.335 inches
Mounting Method:
Terminal
Terminal Circle Diameter:
Between 0.016 inches and 0.021 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
500.0 reverse voltage, peak
Test Data Document:
81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quantity:
3 uninsulated wire lead
Specification Data:
81349-mil-s-19500/276 government specification
Shelf Life:
N/a
Unit Of Measure:

Demilitarization:
Yes - demil/mli
Fiig: